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#### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

#### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	667MHz
Co-Processors/DSP	Security; SEC
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (2)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	Cryptography, Random Number Generator
Package / Case	672-LBGA
Supplier Device Package	672-LBGA (35x35)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8349ezualfb">https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8349ezualfb</a>

## 4.3 TSEC Gigabit Reference Clock Timing

Table 8 provides the TSEC gigabit reference clocks (EC\_GTX\_CLK125) AC timing specifications.

**Table 8. EC\_GTX\_CLK125 AC Timing Specifications**

At recommended operating conditions with  $LV_{DD} = 2.5 \pm 0.125 \text{ mV}/3.3 \text{ V} \pm 165 \text{ mV}$

Parameter	Symbol	Min	Typical	Max	Unit	Notes
EC_GTX_CLK125 frequency	$t_{G125}$	—	125	—	MHz	—
EC_GTX_CLK125 cycle time	$t_{G125}$	—	8	—	ns	—
EC_GTX_CLK125 rise and fall time $LV_{DD} = 2.5 \text{ V}$ $LV_{DD} = 3.3 \text{ V}$	$t_{G125R}/t_{G125F}$	—	—	0.75 1.0	ns	1
EC_GTX_CLK125 duty cycle GMII, TBI 1000Base-T for RGMII, RTBI	$t_{G125H}/t_{G125}$	45 47	—	55 53	%	2
EC_GTX_CLK125 jitter	—	—	—	$\pm 150$	ps	2

**Notes:**

1. Rise and fall times for EC\_GTX\_CLK125 are measured from 0.5 and 2.0 V for  $LV_{DD} = 2.5 \text{ V}$  and from 0.6 and 2.7 V for  $LV_{DD} = 3.3 \text{ V}$ .
2. EC\_GTX\_CLK125 is used to generate the GTX clock for the eTSEC transmitter with 2% degradation. The EC\_GTX\_CLK125 duty cycle can be loosened from 47%/53% as long as the PHY device can tolerate the duty cycle generated by the eTSEC GTX\_CLK. See [Section 8.2.4, “RGMII and RTBI AC Timing Specifications](#) for the duty cycle for 10Base-T and 100Base-T reference clock.

## 5 RESET Initialization

This section describes the DC and AC electrical specifications for the reset initialization timing and electrical requirements of the MPC8349EA.

### 5.1 RESET DC Electrical Characteristics

Table 9 provides the DC electrical characteristics for the RESET pins of the MPC8349EA.

**Table 9. RESET Pins DC Electrical Characteristics<sup>1</sup>**

Parameter	Symbol	Condition	Min	Max	Unit
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	—	—	$\pm 5$	$\mu\text{A}$
Output high voltage <sup>2</sup>	$V_{OH}$	$I_{OH} = -8.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 8.0 \text{ mA}$	—	0.5	V

Table 11 lists the PLL and DLL lock times.

**Table 11. PLL and DLL Lock Times**

Parameter/Condition	Min	Max	Unit	Notes
PLL lock times	—	100	μs	—
DLL lock times	7680	122,880	csb_clk cycles	1, 2

**Notes:**

1. DLL lock times are a function of the ratio between the output clock and the coherency system bus clock (csb\_clk). A 2:1 ratio results in the minimum and an 8:1 ratio results in the maximum.
2. The csb\_clk is determined by the CLKIN and system PLL ratio. See [Section 19, “Clocking.”](#)

## 6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface of the MPC8349EA. Note that DDR SDRAM is  $GV_{DD}(\text{typ}) = 2.5 \text{ V}$  and DDR2 SDRAM is  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$ . The AC electrical specifications are the same for DDR and DRR2 SDRAM.

### NOTE

The information in this document is accurate for revision 3.0 silicon and later. For information on revision 1.1 silicon and earlier versions see the *MPC8349E PowerQUICC II Pro Integrated Host Processor Hardware Specifications*. See [Section 22.1, “Part Numbers Fully Addressed by This Document,”](#) for silicon revision level determination.

### 6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 12 provides the recommended operating conditions for the DDR2 SDRAM component(s) of the MPC8349EA when  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$ .

**Table 12. DDR2 SDRAM DC Electrical Characteristics for  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$**

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	$GV_{DD}$	1.71	1.89	V	1
I/O reference voltage	$MV_{REF}$	$0.49 \times GV_{DD}$	$0.51 \times GV_{DD}$	V	2
I/O termination voltage	$V_{TT}$	$MV_{REF} - 0.04$	$MV_{REF} + 0.04$	V	3
Input high voltage	$V_{IH}$	$MV_{REF} + 0.125$	$GV_{DD} + 0.3$	V	—
Input low voltage	$V_{IL}$	-0.3	$MV_{REF} - 0.125$	V	—
Output leakage current	$I_{OZ}$	-9.9	9.9	μA	4
Output high current ( $V_{OUT} = 1.420 \text{ V}$ )	$I_{OH}$	-13.4	—	mA	—

**Table 12. DDR2 SDRAM DC Electrical Characteristics for  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$  (continued)**

Output low current ( $V_{OUT} = 0.280 \text{ V}$ )	$I_{OL}$	13.4	—	mA	—
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**Notes:**

1.  $GV_{DD}$  is expected to be within 50 mV of the DRAM  $GV_{DD}$  at all times.
2.  $MV_{REF}$  is expected to equal  $0.5 \times GV_{DD}$ , and to track  $GV_{DD}$  DC variations as measured at the receiver. Peak-to-peak noise on  $MV_{REF}$  cannot exceed  $\pm 2\%$  of the DC value.
3.  $V_{TT}$  is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to equal  $MV_{REF}$ . This rail should track variations in the DC level of  $MV_{REF}$ .
4. Output leakage is measured with all outputs disabled,  $0 \text{ V} \leq V_{OUT} \leq GV_{DD}$ .

Table 13 provides the DDR2 capacitance when  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$ .

**Table 13. DDR2 SDRAM Capacitance for  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$** 

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input/output capacitance: DQ, DQS, $\overline{\text{DQS}}$	$C_{IO}$	6	8	pF	1
Delta input/output capacitance: DQ, DQS, $\overline{\text{DQS}}$	$C_{DIO}$	—	0.5	pF	1

**Note:**

1. This parameter is sampled.  $GV_{DD} = 1.8 \text{ V} \pm 0.090 \text{ V}$ ,  $f = 1 \text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

Table 14 provides the recommended operating conditions for the DDR SDRAM component(s) when  $GV_{DD}(\text{typ}) = 2.5 \text{ V}$ .

**Table 14. DDR SDRAM DC Electrical Characteristics for  $GV_{DD}(\text{typ}) = 2.5 \text{ V}$** 

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	$GV_{DD}$	2.375	2.625	V	1
I/O reference voltage	$MV_{REF}$	$0.49 \times GV_{DD}$	$0.51 \times GV_{DD}$	V	2
I/O termination voltage	$V_{TT}$	$MV_{REF} - 0.04$	$MV_{REF} + 0.04$	V	3
Input high voltage	$V_{IH}$	$MV_{REF} + 0.18$	$GV_{DD} + 0.3$	V	—
Input low voltage	$V_{IL}$	-0.3	$MV_{REF} - 0.18$	V	—
Output leakage current	$I_{OZ}$	-9.9	-9.9	$\mu\text{A}$	4
Output high current ( $V_{OUT} = 1.95 \text{ V}$ )	$I_{OH}$	-15.2	—	mA	—
Output low current ( $V_{OUT} = 0.35 \text{ V}$ )	$I_{OL}$	15.2	—	mA	—

**Notes:**

1.  $GV_{DD}$  is expected to be within 50 mV of the DRAM  $GV_{DD}$  at all times.
2.  $MV_{REF}$  is expected to be equal to  $0.5 \times GV_{DD}$ , and to track  $GV_{DD}$  DC variations as measured at the receiver. Peak-to-peak noise on  $MV_{REF}$  may not exceed  $\pm 2\%$  of the DC value.
3.  $V_{TT}$  is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to  $MV_{REF}$ . This rail should track variations in the DC level of  $MV_{REF}$ .
4. Output leakage is measured with all outputs disabled,  $0 \text{ V} \leq V_{OUT} \leq GV_{DD}$ .

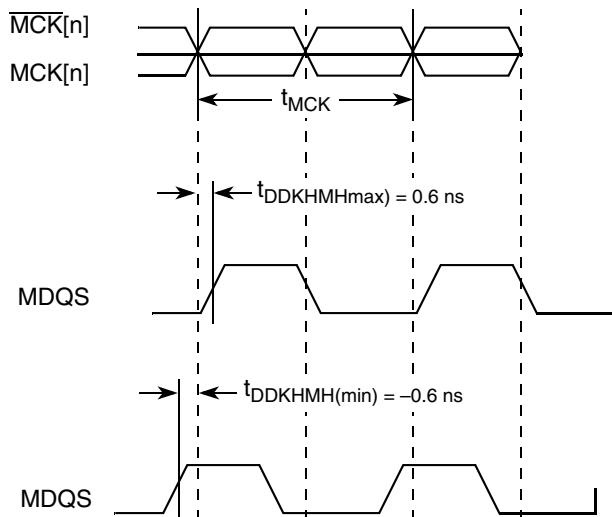
**Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications (continued)**At recommended operating conditions with  $GV_{DD}$  of  $(1.8 \text{ or } 2.5 \text{ V}) \pm 5\%$ .

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
MDQS epilogue end	$t_{DDKHME}$	-0.6	0.6	ns	6

**Notes:**

1. The symbols for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output goes invalid (AX or DX). For example,  $t_{DDKHAS}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes from the high (H) state until outputs (A) are set up (S) or output valid time. Also,  $t_{DDKLDX}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
2. All MCK/ $\overline{MCK}$  referenced measurements are made from the crossing of the two signals  $\pm 0.1 \text{ V}$ .
3. ADDR/CMD includes all DDR SDRAM output signals except MCK/ $\overline{MCK}$ ,  $\overline{MCS}$ , and MDQ/MECC/MDM/MDQS. For the ADDR/CMD setup and hold specifications, it is assumed that the clock control register is set to adjust the memory clocks by 1/2 applied cycle.
4.  $t_{DDKHMH}$  follows the symbol conventions described in note 1. For example,  $t_{DDKHMH}$  describes the DDR timing (DD) from the rising edge of the MCK(n) clock (KH) until the MDQS signal is valid (MH).  $t_{DDKHMH}$  can be modified through control of the DQSS override bits in the TIMING\_CFG\_2 register and is typically set to the same delay as the clock adjust in the CLK\_CNTL register. The timing parameters listed in the table assume that these two parameters are set to the same adjustment value. See the *MPC8349EA PowerQUICC II Pro Integrated Host Processor Family Reference Manual* for the timing modifications enabled by use of these bits.
5. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe should be centered inside the data eye at the pins of the microprocessor.
6. All outputs are referenced to the rising edge of MCK(n) at the pins of the microprocessor. Note that  $t_{DDKHMH}$  follows the symbol conventions described in note 1.

Figure 6 shows the DDR SDRAM output timing for the MCK to MDQS skew measurement ( $t_{DDKHMH}$ ).

**Figure 6. Timing Diagram for  $t_{DDKHMH}$**

## 8.1.1 TSEC DC Electrical Characteristics

GMII, MII, TBI, RGMII, and RTBI drivers and receivers comply with the DC parametric attributes specified in [Table 23](#) and [Table 24](#). The RGMII and RTBI signals in [Table 24](#) are based on a 2.5-V CMOS interface voltage as defined by JEDEC EIA/JESD8-5.

**Table 23. GMII/TBI and MII DC Electrical Characteristics**

Parameter	Symbol	Conditions		Min	Max	Unit
Supply voltage 3.3 V	$LV_{DD}^2$	—		2.97	3.63	V
Output high voltage	$V_{OH}$	$I_{OH} = -4.0$ mA	$LV_{DD} = \text{Min}$	2.40	$LV_{DD} + 0.3$	V
Output low voltage	$V_{OL}$	$I_{OL} = 4.0$ mA	$LV_{DD} = \text{Min}$	GND	0.50	V
Input high voltage	$V_{IH}$	—	—	2.0	$LV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	—	-0.3	0.90	V
Input high current	$I_{IH}$	$V_{IN}^1 = LV_{DD}$		—	40	$\mu A$
Input low current	$I_{IL}$	$V_{IN}^1 = \text{GND}$		-600	—	$\mu A$

**Notes:**

1. The symbol  $V_{IN}$ , in this case, represents the  $LV_{IN}$  symbol referenced in [Table 1](#) and [Table 2](#).
2. GMII/MII pins not needed for RGMII or RTBI operation are powered by the  $OV_{DD}$  supply.

**Table 24. RGMII/RTBI (When Operating at 2.5 V) DC Electrical Characteristics**

Parameters	Symbol	Conditions		Min	Max	Unit
Supply voltage 2.5 V	$LV_{DD}$	—		2.37	2.63	V
Output high voltage	$V_{OH}$	$I_{OH} = -1.0$ mA	$LV_{DD} = \text{Min}$	2.00	$LV_{DD} + 0.3$	V
Output low voltage	$V_{OL}$	$I_{OL} = 1.0$ mA	$LV_{DD} = \text{Min}$	GND - 0.3	0.40	V
Input high voltage	$V_{IH}$	—	$LV_{DD} = \text{Min}$	1.7	$LV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	$LV_{DD} = \text{Min}$	-0.3	0.70	V
Input high current	$I_{IH}$	$V_{IN}^1 = LV_{DD}$		—	10	$\mu A$
Input low current	$I_{IL}$	$V_{IN}^1 = \text{GND}$		-15	—	$\mu A$

**Note:**

1. The symbol  $V_{IN}$ , in this case, represents the  $LV_{IN}$  symbol referenced in [Table 1](#) and [Table 2](#).

## 8.2 GMII, MII, TBI, RGMII, and RTBI AC Timing Specifications

The AC timing specifications for GMII, MII, TBI, RGMII, and RTBI are presented in this section.

### 8.2.1 GMII Timing Specifications

This section describes the GMII transmit and receive AC timing specifications.

## 9 USB

This section provides the AC and DC electrical specifications for the USB interface of the MPC8349EA.

### 9.1 USB DC Electrical Characteristics

[Table 35](#) provides the DC electrical characteristics for the USB interface.

**Table 35. USB DC Electrical Characteristics**

Parameter	Symbol	Min	Max	Unit
High-level input voltage	$V_{IH}$	2	$OV_{DD} + 0.3$	V
Low-level input voltage	$V_{IL}$	-0.3	0.8	V
Input current	$I_{IN}$	—	$\pm 5$	$\mu A$
High-level output voltage, $I_{OH} = -100 \mu A$	$V_{OH}$	$OV_{DD} - 0.2$	—	V
Low-level output voltage, $I_{OL} = 100 \mu A$	$V_{OL}$	—	0.2	V

### 9.2 USB AC Electrical Specifications

[Table 36](#) describes the general timing parameters of the USB interface of the MPC8349EA.

**Table 36. USB General Timing Parameters (ULPI Mode Only)**

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
USB clock cycle time	$t_{USCK}$	15	—	ns	2–5
Input setup to USB clock—all inputs	$t_{USIVKH}$	4	—	ns	2–5
Input hold to USB clock—all inputs	$t_{USIXKH}$	1	—	ns	2–5
USB clock to output valid—all outputs	$t_{USKHOV}$	—	7	ns	2–5
Output hold from USB clock—all outputs	$t_{USKHOX}$	2	—	ns	2–5

**Notes:**

1. The symbols for timing specifications follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{USIXKH}$  symbolizes USB timing (US) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also,  $t_{USKHOX}$  symbolizes USB timing (US) for the USB clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to USB clock.
3. All signals are measured from  $OV_{DD}/2$  of the rising edge of the USB clock to  $0.4 \times OV_{DD}$  of the signal in question for 3.3 V signaling levels.
4. Input timings are measured at the pin.
5. For active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to that of the leakage current specification.

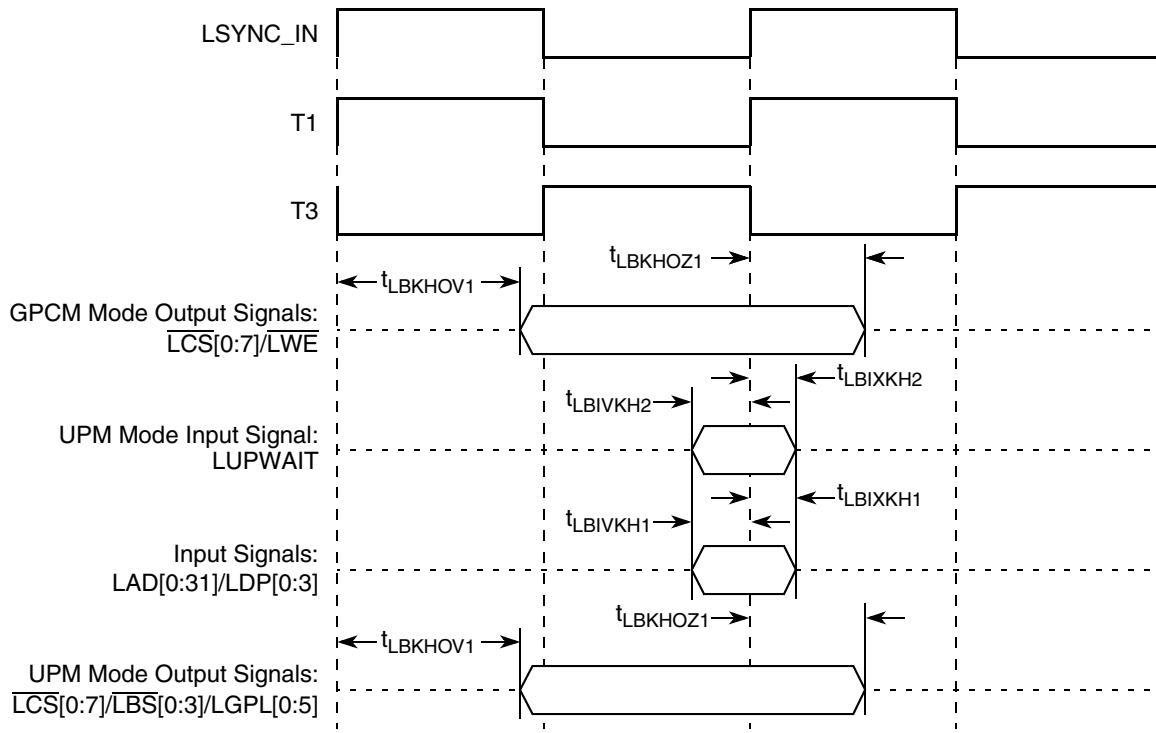


Figure 23. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 2 (DLL Enabled)

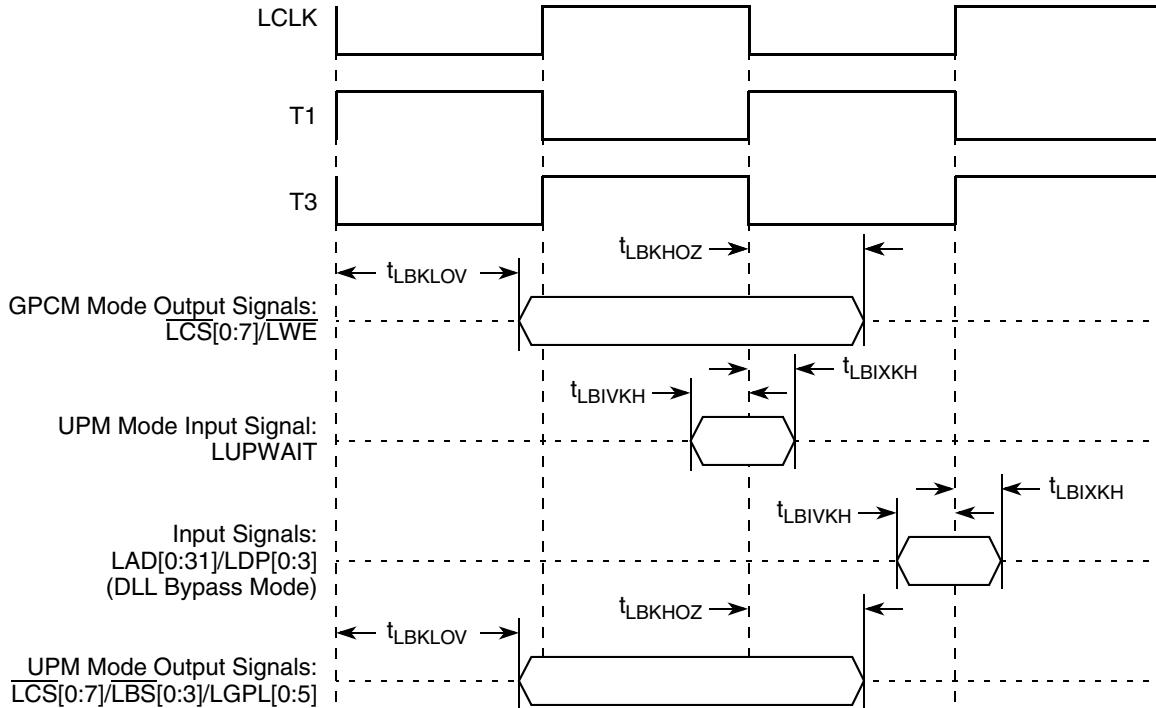


Figure 24. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 2 (DLL Bypass Mode)

**Table 45. PCI AC Timing Specifications at 66 MHz<sup>1</sup> (continued)**

Parameter	Symbol <sup>2</sup>	Min	Max	Unit	Notes
PORESET to REQ64 hold time	tPCRHRX	0	50	ns	6

**Notes:**

1. PCI timing depends on M66EN and the ratio between PCI1/PCI2. Refer to the PCI chapter of the reference manual for a description of M66EN.
2. The symbols for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
3. See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
4. For active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
5. Input timings are measured at the pin.
6. The setup and hold time is with respect to the rising edge of  $\overline{\text{PORESET}}$ .

Table 46 provides the PCI AC timing specifications at 33 MHz.

**Table 46. PCI AC Timing Specifications at 33 MHz**

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Clock to output valid	tPCKHOV	—	11	ns	2
Output hold from clock	tPCKHOX	2	—	ns	2
Clock to output high impedance	tPCKHOZ	—	14	ns	2, 3
Input setup to clock	tPCIVKH	3.0	—	ns	2, 4
Input hold from clock	tPCIXKH	0	—	ns	2, 4
REQ64 to PORESET setup time	tPCRVRH	5	—	clocks	5
PORESET to REQ64 hold time	tPCRHRX	0	50	ns	5

**Notes:**

1. The symbols for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
2. See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
3. For active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
4. Input timings are measured at the pin.
5. The setup and hold time is with respect to the rising edge of  $\overline{\text{PORESET}}$ .

Figure 34 provides the AC test load for PCI.

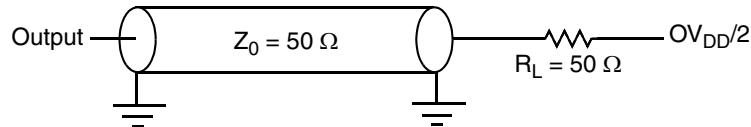


Figure 34. PCI AC Test Load

Figure 35 shows the PCI input AC timing diagram.

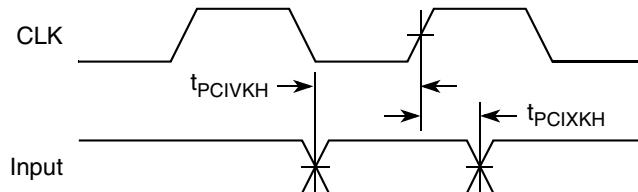


Figure 35. PCI Input AC Timing Diagram

Figure 36 shows the PCI output AC timing diagram.

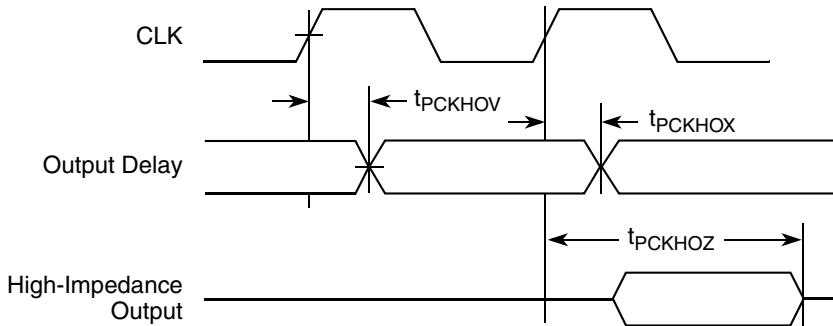


Figure 36. PCI Output AC Timing Diagram

## 14 Timers

This section describes the DC and AC electrical specifications for the timers.

### 14.1 Timer DC Electrical Characteristics

Table 47 provides the DC electrical characteristics for the MPC8349EA timer pins, including TIN,  $\overline{\text{TOUT}}$ ,  $\overline{\text{TGATE}}$ , and RTC\_CLK.

Table 47. Timer DC Electrical Characteristics

Parameter	Symbol	Condition	Min	Max	Unit
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	—	—	$\pm 5$	$\mu A$
Output high voltage	$V_{OH}$	$I_{OH} = -8.0 \text{ mA}$	2.4	—	V

**Table 47. Timer DC Electrical Characteristics (continued)**

Parameter	Symbol	Condition	Min	Max	Unit
Output low voltage	$V_{OL}$	$I_{OL} = 8.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V

## 14.2 Timer AC Timing Specifications

Table 48 provides the timer input and output AC timing specifications.

**Table 48. Timers Input AC Timing Specifications<sup>1</sup>**

Parameter	Symbol <sup>2</sup>	Min	Unit
Timers inputs—minimum pulse width	$t_{TIWID}$	20	ns

**Notes:**

1. Input specifications are measured from the 50 percent level of the signal to the 50 percent level of the rising edge of CLKIN. Timings are measured at the pin.
2. Timer inputs and outputs are asynchronous to any visible clock. Timer outputs should be synchronized before use by external synchronous logic. Timer inputs are required to be valid for at least  $t_{TIWID}$  ns to ensure proper operation.

## 15 GPIO

This section describes the DC and AC electrical specifications for the GPIO.

### 15.1 GPIO DC Electrical Characteristics

Table 49 provides the DC electrical characteristics for the MPC8349EA GPIO.

**Table 49. GPIO DC Electrical Characteristics**

PParameter	Symbol	Condition	Min	Max	Unit
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	—	—	$\pm 5$	$\mu A$
Output high voltage	$V_{OH}$	$I_{OH} = -8.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 8.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V

# 17 SPI

This section describes the SPI DC and AC electrical specifications.

## 17.1 SPI DC Electrical Characteristics

[Table 53](#) provides the SPI DC electrical characteristics.

**Table 53. SPI DC Electrical Characteristics**

Parameter	Symbol	Condition	Min	Max	Unit
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	—	—	$\pm 5$	$\mu A$
Output high voltage	$V_{OH}$	$I_{OH} = -8.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 8.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V

## 17.2 SPI AC Timing Specifications

[Table 54](#) provides the SPI input and output AC timing specifications.

**Table 54. SPI AC Timing Specifications<sup>1</sup>**

Parameter	Symbol <sup>2</sup>	Min	Max	Unit
SPI outputs valid—Master mode (internal clock) delay	$t_{NIKH0V}$	—	6	ns
SPI outputs hold—Master mode (internal clock) delay	$t_{NIKH0X}$	0.5	—	ns
SPI outputs valid—Slave mode (external clock) delay	$t_{NEKH0V}$	—	8	ns
SPI outputs hold—Slave mode (external clock) delay	$t_{NEKH0X}$	2	—	ns
SPI inputs—Master mode (internal clock) input setup time	$t_{NIIVKH}$	4	—	ns
SPI inputs—Master mode (internal clock) input hold time	$t_{NIIKXH}$	0	—	ns
SPI inputs—Slave mode (external clock) input setup time	$t_{NEIVKH}$	4	—	ns
SPI inputs—Slave mode (external clock) input hold time	$t_{NEIXKH}$	2	—	ns

**Notes:**

1. Output specifications are measured from the 50 percent level of the rising edge of CLKIN to the 50 percent level of the signal. Timings are measured at the pin.
2. The symbols for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{NIKH0X}$  symbolizes the internal timing (NI) for the time SPICLK clock reference (K) goes to the high state (H) until outputs (O) are invalid (X).

**Table 55. MPC8349EA (TBGA) Pinout Listing (continued)**

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO1[2]/DMA_DDONE0/ GTM1_TOUT1	B25	I/O	OV <sub>DD</sub>	—
GPIO1[3]/DMA_DREQ1/GTM1_TIN2/ GTM2_TIN1	D24	I/O	OV <sub>DD</sub>	—
GPIO1[4]/DMA_DACK1/ GTM1_TGATE2/GTM2_TGATE1	A25	I/O	OV <sub>DD</sub>	—
GPIO1[5]/DMA_DDONE1/ GTM1_TOUT2/GTM2_TOUT1	B24	I/O	OV <sub>DD</sub>	—
GPIO1[6]/DMA_DREQ2/GTM1_TIN3/ GTM2_TIN4	A24	I/O	OV <sub>DD</sub>	—
GPIO1[7]/DMA_DACK2/ GTM1_TGATE3/GTM2_TGATE4	D23	I/O	OV <sub>DD</sub>	—
GPIO1[8]/DMA_DDONE2/ GTM1_TOUT3	B23	I/O	OV <sub>DD</sub>	—
GPIO1[9]/DMA_DREQ3/GTM1_TIN4/ GTM2_TIN3	A23	I/O	OV <sub>DD</sub>	—
GPIO1[10]/DMA_DACK3/ GTM1_TGATE4/GTM2_TGATE3	F22	I/O	OV <sub>DD</sub>	—
GPIO1[11]/DMA_DDONE3/ GTM1_TOUT4/GTM2_TOUT3	E22	I/O	OV <sub>DD</sub>	—
<b>USB Port 1</b>				
MPH1_D0_ENABLEN/ DR_D0_ENABLEN	A26	I/O	OV <sub>DD</sub>	—
MPH1_D1_SER_TXD/ DR_D1_SER_TXD	B26	I/O	OV <sub>DD</sub>	—
MPH1_D2_VMO_SE0/ DR_D2_VMO_SE0	D25	I/O	OV <sub>DD</sub>	—
MPH1_D3_SPEED/DR_D3_SPEED	A27	I/O	OV <sub>DD</sub>	—
MPH1_D4_DP/DR_D4_DP	B27	I/O	OV <sub>DD</sub>	—
MPH1_D5_DM/DR_D5_DM	C27	I/O	OV <sub>DD</sub>	—
MPH1_D6_SER_RCV/ DR_D6_SER_RCV	D26	I/O	OV <sub>DD</sub>	—
MPH1_D7_DRVVBUS/ DR_D7_DRVVBUS	E26	I/O	OV <sub>DD</sub>	—
MPH1_NXT/DR_SESS_VLD_NXT	D27	I	OV <sub>DD</sub>	—
MPH1_DIR_DPPULLUP/ DR_XCVR_SEL_DPPULLUP	A28	I/O	OV <sub>DD</sub>	—
MPH1_STP_SUSPEND/ DR_STP_SUSPEND	F26	O	OV <sub>DD</sub>	—

**Table 55. MPC8349EA (TBGA) Pinout Listing (continued)**

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MPH1_PWRFAULT/ DR_RX_ERROR_PWRFAULT	E27	I	OV <sub>DD</sub>	—
MPH1_PCTL0/DR_TX_VALID_PCTL0	A29	O	OV <sub>DD</sub>	—
MPH1_PCTL1/DR_TX_VALIDH_PCTL1	D28	O	OV <sub>DD</sub>	—
MPH1_CLK/DR_CLK	B29	I	OV <sub>DD</sub>	—
<b>USB Port 0</b>				
MPH0_D0_ENABLEN/ DR_D8_CHGVBUS	C29	I/O	OV <sub>DD</sub>	—
MPH0_D1_SER_TXD/ DR_D9_DCHGVBUS	A30	I/O	OV <sub>DD</sub>	—
MPH0_D2_VMO_SE0/DR_D10_DPPD	E28	I/O	OV <sub>DD</sub>	—
MPH0_D3_SPEED/DR_D11_DMMD	B30	I/O	OV <sub>DD</sub>	—
MPH0_D4_DP/DR_D12_VBUS_VLD	C30	I/O	OV <sub>DD</sub>	—
MPH0_D5_DM/DR_D13_SESS_END	A31	I/O	OV <sub>DD</sub>	—
MPH0_D6_SER_RCV/DR_D14	B31	I/O	OV <sub>DD</sub>	—
MPH0_D7_DRVVBUS/ DR_D15_IDPULLUP	C31	I/O	OV <sub>DD</sub>	—
MPH0_NXT/DR_RX_ACTIVE_ID	B32	I	OV <sub>DD</sub>	—
MPH0_DIR_DPPULLUP/DR_RESET	A32	I/O	OV <sub>DD</sub>	—
MPH0_STP_SUSPEND/ DR_TX_READY	A33	I/O	OV <sub>DD</sub>	—
MPH0_PWRFAULT/DR_RX_VALIDH	C32	I	OV <sub>DD</sub>	—
MPH0_PCTL0/DR_LINE_STATE0	D31	I/O	OV <sub>DD</sub>	—
MPH0_PCTL1/DR_LINE_STATE1	E30	I/O	OV <sub>DD</sub>	—
MPH0_CLK/DR_RX_VALID	B33	I	OV <sub>DD</sub>	—
<b>Programmable Interrupt Controller</b>				
MCP_OUT	AN33	O	OV <sub>DD</sub>	2
IRQ0/MCP_IN/GPIO2[12]	C19	I/O	OV <sub>DD</sub>	—
IRQ[1:5]/GPIO2[13:17]	C22, A22, D21, C21, B21	I/O	OV <sub>DD</sub>	—
IRQ[6]/GPIO2[18]/CKSTOP_OUT	A21	I/O	OV <sub>DD</sub>	—
IRQ[7]/GPIO2[19]/CKSTOP_IN	C20	I/O	OV <sub>DD</sub>	—
<b>Ethernet Management Interface</b>				
EC_MDC	A7	O	LV <sub>DD1</sub>	—
EC_MDIO	E9	I/O	LV <sub>DD1</sub>	11

**Table 55. MPC8349EA (TBGA) Pinout Listing (continued)**

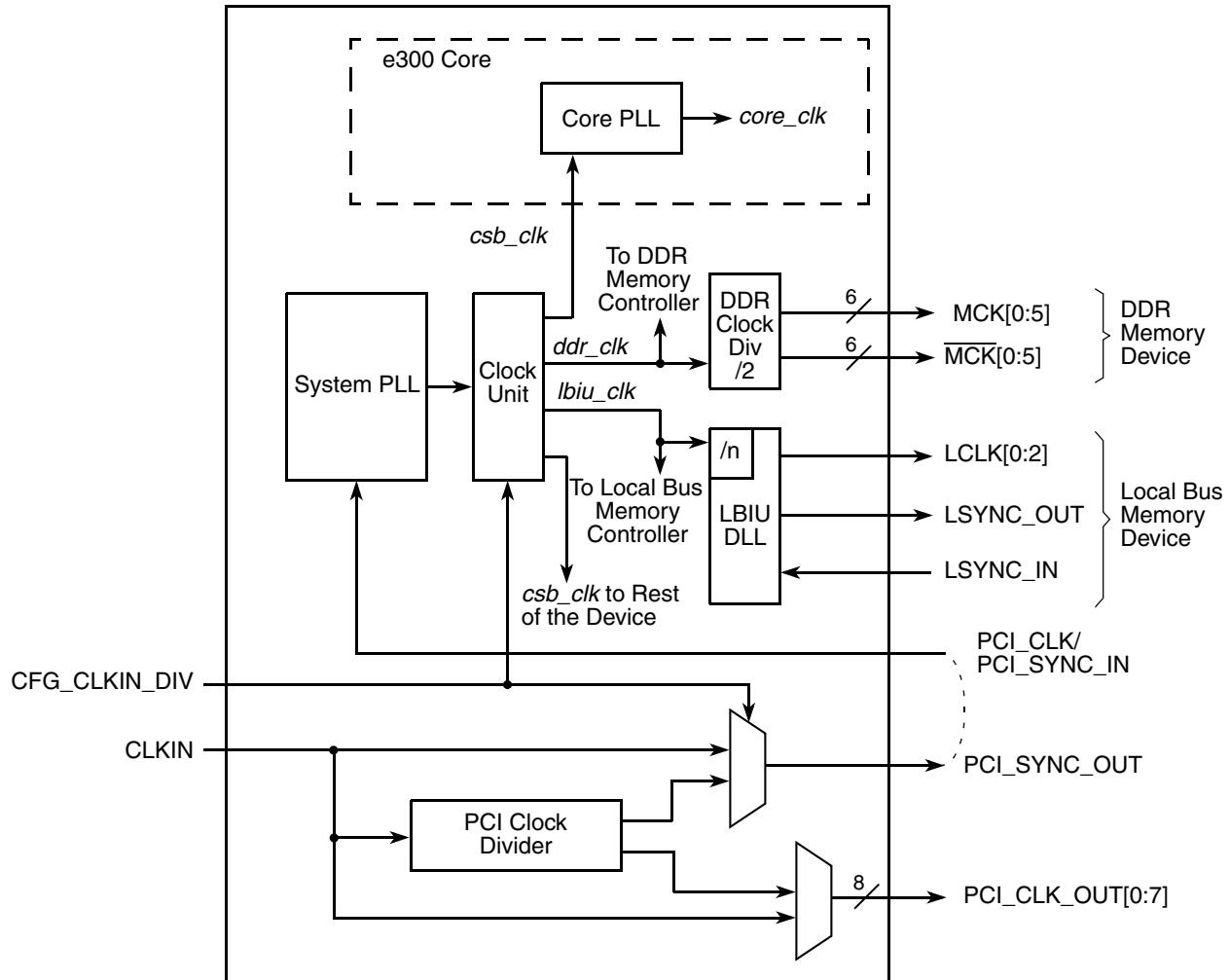
Signal	Package Pin Number	Pin Type	Power Supply	Notes
<b>Gigabit Reference Clock</b>				
EC_GTX_CLK125	C8	I	LV <sub>DD1</sub>	—
<b>Three-Speed Ethernet Controller (Gigabit Ethernet 1)</b>				
TSEC1_COL/GPIO2[20]	A17	I/O	OV <sub>DD</sub>	—
TSEC1_CRS/GPIO2[21]	F12	I/O	LV <sub>DD1</sub>	—
TSEC1_GTX_CLK	D10	O	LV <sub>DD1</sub>	3
TSEC1_RX_CLK	A11	I	LV <sub>DD1</sub>	—
TSEC1_RX_DV	B11	I	LV <sub>DD1</sub>	—
TSEC1_RX_ER/GPIO2[26]	B17	I/O	OV <sub>DD</sub>	—
TSEC1_RXD[7:4]/GPIO2[22:25]	B16, D16, E16, F16	I/O	OV <sub>DD</sub>	—
TSEC1_RXD[3:0]	E10, A8, F10, B8	I	LV <sub>DD1</sub>	—
TSEC1_TX_CLK	D17	I	OV <sub>DD</sub>	—
TSEC1_TXD[7:4]/GPIO2[27:30]	A15, B15, A14, B14	I/O	OV <sub>DD</sub>	—
TSEC1_TXD[3:0]	A10, E11, B10, A9	O	LV <sub>DD1</sub>	10
TSEC1_TX_EN	B9	O	LV <sub>DD1</sub>	—
TSEC1_TX_ER/GPIO2[31]	A16	I/O	OV <sub>DD</sub>	—
<b>Three-Speed Ethernet Controller (Gigabit Ethernet 2)</b>				
TSEC2_COL/GPIO1[21]	C14	I/O	OV <sub>DD</sub>	—
TSEC2_CRS/GPIO1[22]	D6	I/O	LV <sub>DD2</sub>	—
TSEC2_GTX_CLK	A4	O	LV <sub>DD2</sub>	—
TSEC2_RX_CLK	B4	I	LV <sub>DD2</sub>	—
TSEC2_RX_DV/GPIO1[23]	E6	I/O	LV <sub>DD2</sub>	—
TSEC2_RXD[7:4]/GPIO1[26:29]	A13, B13, C13, A12	I/O	OV <sub>DD</sub>	—
TSEC2_RXD[3:0]/GPIO1[13:16]	D7, A6, E8, B7	I/O	LV <sub>DD2</sub>	—
TSEC2_RX_ER/GPIO1[25]	D14	I/O	OV <sub>DD</sub>	—
TSEC2_TXD[7]/GPIO1[31]	B12	I/O	OV <sub>DD</sub>	—
TSEC2_TXD[6]/DR_XCVR_TERM_SEL	C12	O	OV <sub>DD</sub>	—
TSEC2_TXD[5]/DR_UTMI_OPMODE1	D12	O	OV <sub>DD</sub>	—
TSEC2_TXD[4]/DR_UTMI_OPMODE0	E12	O	OV <sub>DD</sub>	—
TSEC2_TXD[3:0]/GPIO1[17:20]	B5, A5, F8, B6	I/O	LV <sub>DD2</sub>	—

**Table 55. MPC8349EA (TBGA) Pinout Listing (continued)**

Signal	Package Pin Number	Pin Type	Power Supply	Notes
TSEC2_TX_ER/GPIO1[24]	F14	I/O	OV <sub>DD</sub>	—
TSEC2_TX_EN/GPIO1[12]	C5	I/O	LV <sub>DD2</sub>	—
TSEC2_TX_CLK/GPIO1[30]	E14	I/O	OV <sub>DD</sub>	—
<b>DUART</b>				
UART_SOUT[1:2]/MSRCID[0:1]/LSRCID[0:1]	AK27, AN29	O	OV <sub>DD</sub>	—
UART_SIN[1:2]/MSRCID[2:3]/LSRCID[2:3]	AL28, AM29	I/O	OV <sub>DD</sub>	—
UART_CTS[1]/MSRCID4/LSRCID4	AP30	I/O	OV <sub>DD</sub>	—
UART_CTS[2]/MDVAL/ LDVAL	AN30	I/O	OV <sub>DD</sub>	—
UART_RTS[1:2]	AP31, AM30	O	OV <sub>DD</sub>	—
<b>I<sup>2</sup>C interface</b>				
IIC1_SDA	AK29	I/O	OV <sub>DD</sub>	2
IIC1_SCL	AP32	I/O	OV <sub>DD</sub>	2
IIC2_SDA	AN31	I/O	OV <sub>DD</sub>	2
IIC2_SCL	AM31	I/O	OV <sub>DD</sub>	2
<b>SPI</b>				
SPIMOSI/LCS[6]	AN32	I/O	OV <sub>DD</sub>	—
SPIMISO/LCS[7]	AP33	I/O	OV <sub>DD</sub>	—
SPICLK	AK30	I/O	OV <sub>DD</sub>	—
SPISEL	AL31	I	OV <sub>DD</sub>	—
<b>Clocks</b>				
PCI_CLK_OUT[0:2]	AN9, AP9, AM10,	O	OV <sub>DD</sub>	—
PCI_CLK_OUT[3]/LCS[6]	AN10	O	OV <sub>DD</sub>	—
PCI_CLK_OUT[4]/LCS[7]	AJ11	O	OV <sub>DD</sub>	—
PCI_CLK_OUT[5:7]	AP10, AL11, AM11	O	OV <sub>DD</sub>	—
PCI_SYNC_IN/PCI_CLOCK	AK12	I	OV <sub>DD</sub>	—
PCI_SYNC_OUT	AP11	O	OV <sub>DD</sub>	3
RTC/PIT_CLOCK	AM32	I	OV <sub>DD</sub>	—
CLKIN	AM9	I	OV <sub>DD</sub>	—
<b>JTAG</b>				
TCK	E20	I	OV <sub>DD</sub>	—
TDI	F20	I	OV <sub>DD</sub>	4

# 19 Clocking

Figure 41 shows the internal distribution of the clocks.



**Figure 41. MPC8349EA Clock Subsystem**

The primary clock source can be one of two inputs, CLKIN or PCI\_CLK, depending on whether the device is configured in PCI host or PCI agent mode. When the MPC8349EA is configured as a PCI host device, CLKIN is its primary input clock. CLKIN feeds the PCI clock divider ( $\div 2$ ) and the multiplexors for PCI\_SYNC\_OUT and PCI\_CLK\_OUT. The CFG\_CLKIN\_DIV configuration input selects whether CLKIN or CLKIN/2 is driven out on the PCI\_SYNC\_OUT signal. The OCCR[PCICDn] parameters select whether CLKIN or CLKIN/2 is driven out on the PCI\_CLK\_OUTn signals.

PCI\_SYNC\_OUT is connected externally to PCI\_SYNC\_IN to allow the internal clock subsystem to synchronize to the system PCI clocks. PCI\_SYNC\_OUT must be connected properly to PCI\_SYNC\_IN, with equal delay to all PCI agent devices in the system, to allow the MPC8349EA to function. When the device is configured as a PCI agent device, PCI\_CLK is the primary input clock and the CLKIN signal should be tied to GND.

**Table 57** provides the operating frequencies for the MPC8349EA TBGA under recommended operating conditions (see **Table 2**).

**Table 57. Operating Frequencies for TBGA**

Characteristic <sup>1</sup>	400 MHz	533 MHz	667 MHz	Unit
e300 core frequency ( <i>core_clk</i> )	266–400	266–533	266–667	MHz
Coherent system bus frequency ( <i>csb_clk</i> )	100–266	100–333	100–333	MHz
DDR1 memory bus frequency (MCK) <sup>2</sup>	100–133	100–133	100–166.67	MHz
DDR2 memory bus frequency (MCK) <sup>3</sup>	100–133	100–133	100–200	MHz
Local bus frequency (LCLKn) <sup>4</sup>	16.67–133	16.67–133	16.67–133	MHz
PCI input frequency (CLKIN or PCI_CLK)	25–66	25–66	25–66	MHz
Security core maximum internal operating frequency	133	133	166	MHz
USB_DR, USB MPH maximum internal operating frequency	133	133	166	MHz

<sup>1</sup> The CLKIN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen so that the resulting *csb\_clk*, MCK, LCLK[0:2], and *core\_clk* frequencies do not exceed their respective maximum or minimum operating frequencies. The value of SCCR[ENCCM], SCCR[USBDRCM] and SCCR[USBMPHCM] must be programmed so that the maximum internal operating frequency of the security core and USB modules does not exceed the respective values listed in this table.

<sup>2</sup> The DDR data rate is 2x the DDR memory bus frequency.

<sup>3</sup> The DDR data rate is 2x the DDR memory bus frequency.

<sup>4</sup> The local bus frequency is 1/2, 1/4, or 1/8 of the *Ibiu\_clk* frequency (depending on LCCR[CLKDIV]) which is in turn 1x or 2x the *csb\_clk* frequency (depending on RCWL[LBIUCM]).

All frequency combinations shown in the table below may not be available. Maximum operating frequencies depend on the part ordered, see [Section 22.1, “Part Numbers Fully Addressed by This Document,”](#) for part ordering details and contact your Freescale Sales Representative or authorized distributor for more information.

## 19.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. **Table 58** shows the multiplication factor encodings for the system PLL.

**Table 58. System PLL Multiplication Factors**

RCWL[SPMF]	System PLL Multiplication Factor
0000	× 16
0001	Reserved
0010	× 2
0011	× 3
0100	× 4
0101	× 5
0110	× 6

**Table 58. System PLL Multiplication Factors (continued)**

RCWL[SPMF]	System PLL Multiplication Factor
0111	× 7
1000	× 8
1001	× 9
1010	× 10
1011	× 11
1100	× 12
1101	× 13
1110	× 14
1111	× 15

As described in [Section 19, “Clocking,”](#) the LBIUCM, DDRCM, and SPMF parameters in the reset configuration word low and the CFG\_CLKIN\_DIV configuration input signal select the ratio between the primary clock input (CLKIN or PCI\_CLK) and the internal coherent system bus clock (*csb\_clk*). [Table 59](#) and [Table 60](#) show the expected frequency values for the CSB frequency for select *csb\_clk* to CLKIN/PCI\_SYNC\_IN ratios.

**Table 59. CSB Frequency Options for Host Mode**

CFG_CLKIN_DIV at Reset <sup>1</sup>	SPMF	<i>csb_clk</i> : Input Clock Ratio <sup>2</sup>	Input Clock Frequency (MHz) <sup>2</sup>			
			16.67	25	33.33	66.67
			<i>csb_clk</i> Frequency (MHz)			
Low	0010	2 : 1				133
Low	0011	3 : 1			100	200
Low	0100	4 : 1		100	133	266
Low	0101	5 : 1		125	166	333

## 19.3 Suggested PLL Configurations

Table 62 shows suggested PLL configurations for 33 and 66 MHz input clocks.

**Table 62. Suggested PLL Configurations**

Ref No. <sup>1</sup>	RCWL		400 MHz Device			533 MHz Device			667 MHz Device		
	SPMF	CORE PLL	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)
33 MHz CLKIN/PCI_CLK Options											
922	1001	0100010	—	—	—	—	—	f300	33	300	300
723	0111	0100011	33	233	350	33	233	350	33	233	350
604	0110	0000100	33	200	400	33	200	400	33	200	400
624	0110	0100100	33	200	400	33	200	400	33	200	400
803	1000	0000011	33	266	400	33	266	400	33	266	400
823	1000	0100011	33	266	400	33	266	400	33	266	400
903	1001	0000011	—	—	—	33	300	450	33	300	450
923	1001	0100011	—	—	—	33	300	450	33	300	450
704	0111	0000011	—	—	—	33	233	466	33	233	466
724	0111	0100011	—	—	—	33	233	466	33	233	466
A03	1010	0000011	—	—	—	33	333	500	33	333	500
804	1000	0000100	—	—	—	33	266	533	33	266	533
705	0111	0000101	—	—	—	—	—	—	33	233	583
606	0110	0000110	—	—	—	—	—	—	33	200	600
904	1001	0000100	—	—	—	—	—	—	33	300	600
805	1000	0000101	—	—	—	—	—	—	33	266	667
A04	1010	0000100	—	—	—	—	—	—	33	333	667
66 MHz CLKIN/PCI_CLK Options											
304	0011	0000100	66	200	400	66	200	400	66	200	400
324	0011	0100100	66	200	400	66	200	400	66	200	400
403	0100	0000011	66	266	400	66	266	400	66	266	400
423	0100	0100011	66	266	400	66	266	400	66	266	400
305	0011	0000101	—	—	—	66	200	500	66	200	500
503	0101	0000011	—	—	—	66	333	500	66	333	500
404	0100	0000100	—	—	—	66	266	533	66	266	533

## 22.1 Part Numbers Fully Addressed by This Document

**Table 66** shows an analysis of the Freescale part numbering nomenclature for the MPC8349EA. The individual part numbers correspond to a maximum processor core frequency. Each part number also contains a revision code that refers to the die mask revision number. For available frequency configuration parts including extended temperatures, refer to the device product summary page on our website listed on the back cover of this document or, contact your local Freescale sales office.

**Table 66. Part Numbering Nomenclature**

MPC	nnnn	e	t	pp	aa	a	r
Product Code	Part Identifier	Encryption Acceleration	Temperature <sup>1</sup> Range	Package <sup>2</sup>	Processor Frequency <sup>3</sup>	Platform Frequency	Revision Level
MPC	8349	Blank = Not included E = included	Blank = 0 to 105°C C = -40 to 105°C	ZU =TBGA VV = PB free TBGA	e300 core speed AG = 400 AJ = 533 AL = 667	D = 266 F = 333 <sup>4</sup>	B = 3.1

**Notes:**

1. For temperature range = C, processor frequency is limited to with a platform frequency of 266 and up to 533 with a platform frequency of 333
2. See [Section 18, “Package and Pin Listings,”](#) for more information on available package types.
3. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by Part Number Specifications may support other maximum core frequencies.
4. ALF marked parts support DDR1 data rate up to 333 MHz (at 333 MHz CSB as the 'F' marking implies) and DDR2 data rate up to 400 MHz (at 200 MHz CSB). AJF marked parts support DDR1 and DDR2 data rate up to 333 MHz (at a CSB of 333 MHz).

**Table 67** shows the SVR settings by device and package type.

**Table 67. SVR Settings**

Device	Package	SVR (Rev. 3.0)
MPC8349EA	TBGA	8050_0030
MPC8349A	TBGA	8051_0030